DM114 · DM115

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8-Bit CONSTANT CURRENT LED DRIVERS with

3.3v ~ 5v supply voltage

DM114 DM115

8-Bit CONSTANT CURRENT LED DRIVERS with 3.3v ~ 5v Supply Voltage

General Description

The DM114 \cdot DM115 is the constant current driver specifically designed for LED display applications. The value of constant current can be varied using an external resistor. The devices include an 8-bit shift register, latches, and constant current drivers on a single Silicon CMOS chip.

Features

Maximum Output Voltage: 17V

Maximum Clock Frequency: 25MHz (Cascade Operation)

• Power Supply Voltage: 3.3V to 5.0V

CMOS Compatible Input

Package: PDIP16, SOP16, SSOP16

• Package and Pin Layout: Pin layout and functionality are similar to those of the ST2221A.

(Each characteristic value is different.)

• Constant Current Matching: $(Ta = 25^{\circ}C \cdot VDD = 5.0V)$

Chip-to-Chip: ± 10.0%

DM114: Bit-to-Bit: $\pm 4.0\%$ @ IouT = $30 \sim 90$ mA

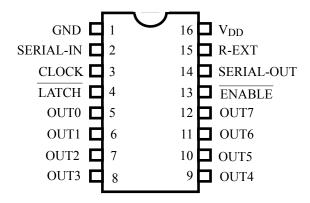
 $\pm 6.0\%$ (a) IOUT = $20 \sim 30$ mA

DM115: Bit-to-Bit: $\pm 4.0\%$ @ IouT = $20 \sim 60$ mA

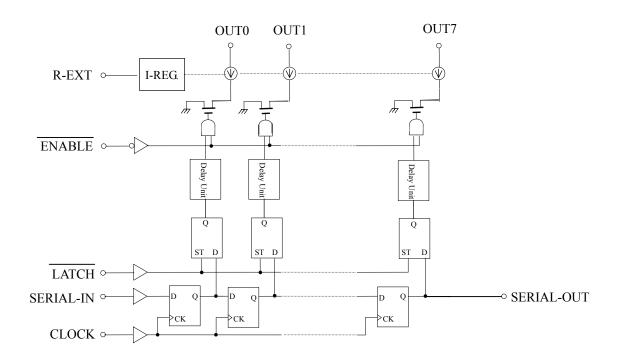
 $\pm 6.0\%$ @ **IOUT** = $5 \sim 20$ mA



Pin Connection (Top view)

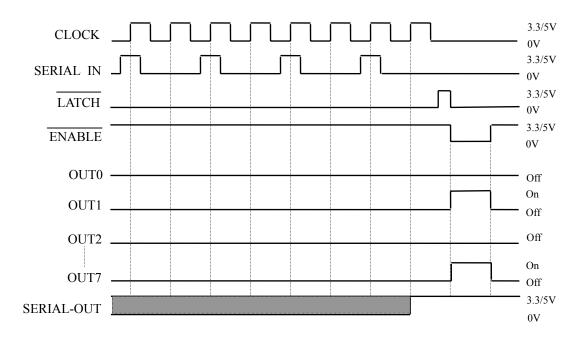


Block Diagram





Timing Diagram



(Note) Latches are level sensitive (not edge triggered).

 $\overline{\text{LATCH}}$ -terminal = H level, latches become transparent; $\overline{\text{LATCH}}$ -terminal = L level, latches hold data.

 $\overline{\text{ENABLE}}$ -terminal = H level, all outputs (OUT0 \sim 7) are off.

An external resistor is connected between R-EXT and GND for setting up the value of constant current.

SERIAL-OUT changes state on the rising edges of clock.

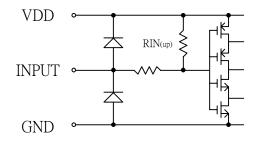
Pin Description

PIN No.	PIN NAME	FUNCTION
1	GND	GND terminal
2	SERIAL-IN	Input terminal of a data shift register
3	CLOCK	Input terminal of a clock for shift register
4	LATCH	Input terminal for data strobe
5~12	OUT0~7	Output terminals
13	ENABLE	Input terminal for output enable (active low)
14	SERIAL-OUT	Output terminal of a data shift register
15	R-EXT	Input terminal of an external resistor
16	$V_{ m DD}$	3.3/5V Supply voltage terminal

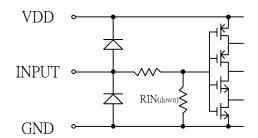


Equivalent Circuit of Inputs and Outputs

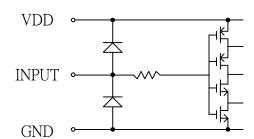
1. ENABLE terminal



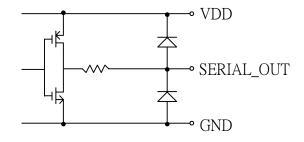
2. LATCH terminal



3. CLOCK, SERIAL-IN terminal



4. SERIAL-OUT terminal





$\label{eq:maximum Ratings (Ta = 25°C, Tj_{(max)} = 150°C)} \textbf{Maximum Ratings (Ta = 25°C, Tj_{(max)} = 150°C)}$

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vdd	0 ~ 7.0	V
Input Voltage	VIN	-0.4 ~ VDD+0.4	V
Output Current	Iout	90 (DM114)	т Л
Output Current	1001	60 (DM115)	— mA
Output Voltage	Vout	- 0.3 ∼ 17	V
Clock Frequency	fclk	25	MHz
GND Terminal Current	IGND	750	т Л
		500	mA
		1.64 (PDIP-16 : Ta=25°C)	
Power Dissipation	PD	1.08 (SOP-16 : Ta=25°C)	W
		0.8 (SSOP-16 : Ta=25°C)	
		76 (PDIP-16)	
Thermal Resistance	Rth(j-a)	115 (SOP-16)	°C/W
		155 (SSOP-16)	
Storage Temperature	Tstg	- 55 ∼ 150	°C

Recommended Operating Condition

CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT	
Supply Voltage	Vdd		3.0	—	5.5	V	
Output Voltage	Vout	_			17	V	
Operating temperature	T_{OPR}		-40	—	85	$^{\circ}\mathbb{C}$	
	Io	OUTn			60	mA	
Output Current	Іон	SERIAL-OUT		—	1.0		
	Iol	SERIAL-OUT			-1.0		
Lugart Voltage	Vih	_	0.7VDD	1	VDD+0.3	V	
Input Voltage	VIL	_	-0.3		0.3VDD	v	
LATCH Pulse Width	tw LAT		15	_		ns	
CLOCK Pulse Width	tw CLK		15			ns	
Set-up Time for DATA	tsetup(D)	$V_{DD} = 3.0 \sim 5.5 \text{ V}$	10			ns	
Hold Time for DATA	thold(D)		5			ns	
Set-up Time for LATCH	et-up Time for LATCH tsetup(L)		15			ns	
Clock Frequency	Clock Frequency fCLK				25	MHz	
		$Ta = 85^{\circ}C(PDIP-16)$			0.85		
Power Dissipation	PD	$Ta = 85^{\circ}C(SOP-16)$			0.56	W	
		$Ta = 85^{\circ}C(SSOP-16)$			0.41		



Electrical Characteristics (VDD = 5.0 V, Ta = 25°C unless otherwise noted)

CHARACTERISTIC	SYM	BOL	CONDITION		MIN.	TYP.	MAX.	UNIT
Input Voltage "H" Level	VI	Н			0.7VDD		VDD	V
Input Voltage "L" Level	VI	L	-		GND		0.3VDD	·
Output Leakage Current	Io	Н	VOH = 17 V				1.0	uA
	Vo)L	IOL = 1.0 mA, VDD=5V				0.4	
Outrot Valtage (C. OUT)	Voh		IOH = -1.0 mA, VDD=5V		4.6			3.7
Output Voltage (S - OUT)	Vo)L	IOL = 1.0 mA,	IOL = 1.0 mA, VDD=3.3V			0.4	V
	Vo	Ή	IOH = -1.0 mA	., VDD=3.3V	2.7		_	
Output Current (Bit-Bit)	ΔIout	DM114	VOUT = 1.2V	$REXT = 390\Omega$		±1.5	±4	%
Output Current (Bit-Bit)	ΔIout	DM115	(1 channel on)	$REXT = 780\Omega$		11.3		
Output Current	Lout	DM114	VOUT = 1.2V	$REXT = 390\Omega$	36.0	40.0	44.0	mA
(Chip-Chip)	Iout	DM115	(1 channel on)	$REXT = 780\Omega$	18.0	20.0	22.0	ША
Output Voltage Regulation	% / V	Vout	$Vdd = 3.3V \sim 5.0V$			0.1	0.5	% / V
Pull-Up Resistor	RIN	(up)	_		200	400	600	ΚΩ
Pull-Down Resistor	RIN(d	own)			100	200	300	ΚΩ
	Idd (off) VDD=5V	DM114	REXT = OPEN, all outputs off			1.3		mA
Supply Current "OFF"			REXT = 200Ω , OUT0 \sim 7 = off			11.0		
Supply Current Of I		D) (115	REXT = OPEN, all outputs off			5.0		
		DM115	REXT = 300Ω ,	$OUT0 \sim 7 = off$		11.0		IIIA
Supply Current "ON"	Idd (on)	DM114	REXT = 200Ω , OUT0~7 = on REXT = 300Ω , OUT0~7 = on			11.0	_	-
Supply Current Oil	VDD=5V	DM115				11.0		
	Idd (off) VDD=3.3V	DM114	REXT = OPEN, all outputs off			1.1		
Supply Current "OFF"		DM114	REXT = 200Ω ,	REXT = 200Ω , OUT0 \sim 7 = off		10.7		mA
		DM115	REXT = OPEN, all outputs off			1.1		
		DIVITIO	REXT = 300Ω ,	$OUT0 \sim 7 = off$		7.2	_	ША
Supply Current "ON"	Idd (on)	DM114	REXT = 200Ω ,	$OUT0 \sim 7 = on$		10.7		
Supply Cultellt On	VDD=3.3V	DM115	REXT = 300Ω ,	$OU\overline{T0\sim7} = on$		7.2		



Switching Characteristics (Ta = 25 °C unless otherwise noted)

DM114

CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation ENABLE-OU		VDD=5.0V	_	40	80	
Delay Time ("L" to "H")	tрLн	VIH=VDD VIL=GND	_	16	20	ns
Propagation ENABLE-OU		REXT=210Ω		70	140	
Delay Time ("H" to "L")	tрнL	tphl VL=5.0V RL=47Ω	_	16	20	ns
Output Current Rise Time	tor	CL=15pF		250	400	ns
Output Current Fall Time	tof		_	30	50	ns

DM115

CHARACTERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation ENABLE-OUTn	4	VDD=5.0V	_	40	80	
Delay Time ("L" to "H")	tр _L H	VIH=VDD VIL=GND	_	16	20	ns
Propagation ENABLE-OUTn		REXT=630Ω	_	70	140	
Delay Time ("H" to "L")	tрнL	VL=5.0V $RL=150\Omega$	_	16	20	ns
Output Current Rise Time	tor	CL=15pF	_	10	15	ns
Output Current Fall Time	tof			30	50	ns

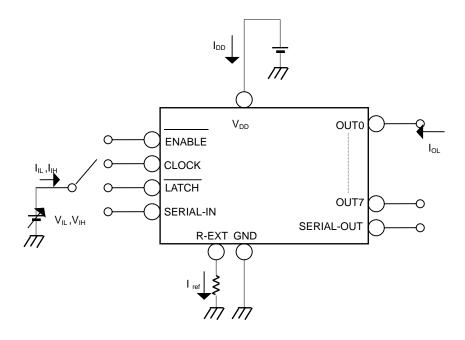
Note: (Delay between outputs)

The DM114 \cdot DM115 also incorporated the delay unit between outputs. The delay time is 4 ns(typ.), out7 has no delay, out5 has 4 ns delay, out 3 has 8 ns delay, and then out 1, out 0, out 2, out 4, out6. The delay is to prevent large current impulse.

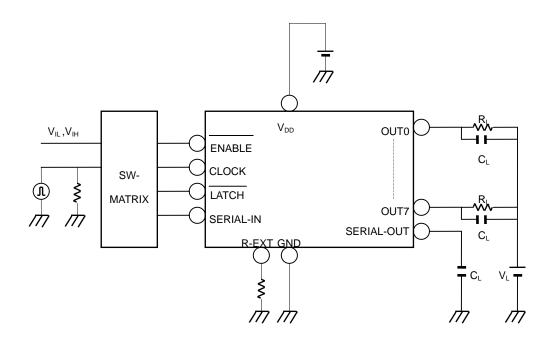


Test Circuit

DC characteristic



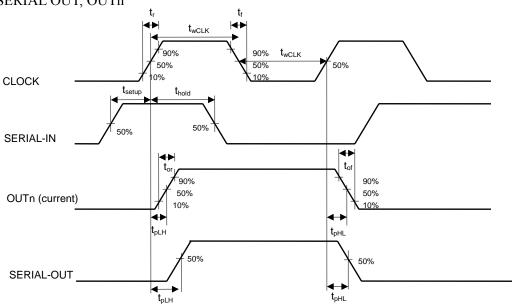
AC characteristic



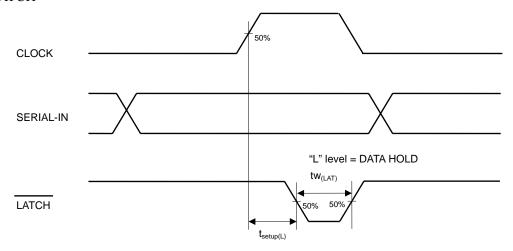


Timing Diagram

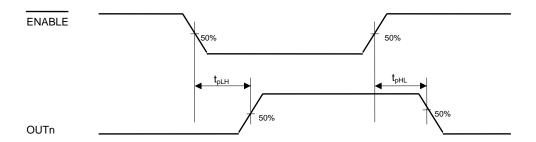
1. CLOCK-SERIAL OUT, OUTn



2. CLOCK-LATCH

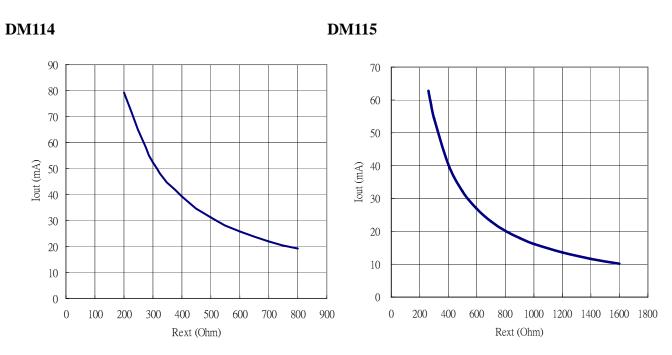


3. ENABLE-OUTn (Current)





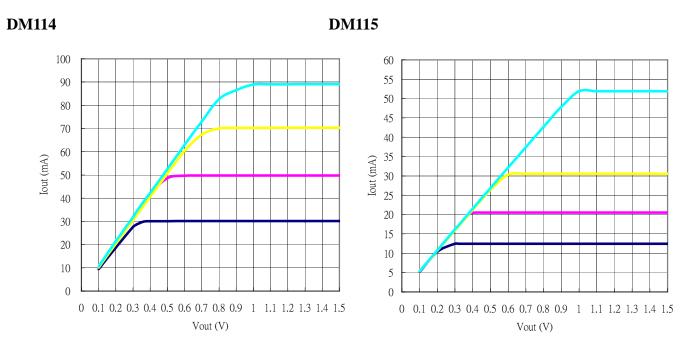
Output Current vs. External Resistor



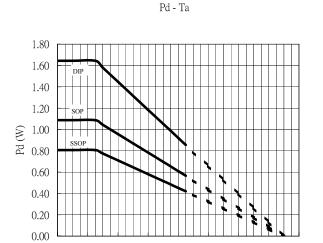
DM114: Iout $\approx 1.3 \text{V} / \text{Rext} * 12$

DM115: Iout $\approx 1.3 \text{V} / \text{Rext} * 12.5$

Output Current Performance vs. Output Voltage



Note: In order to obtain a good constant current output, a suitable output voltage is necessary. Users can get related information about the minimum output voltage from the above graph.



60 _{Ta} 80

100

120

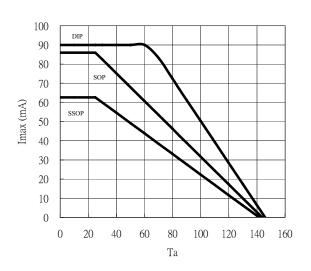
140

160

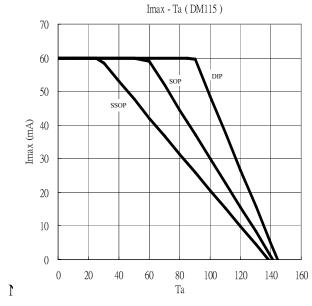
0

20

40



Imax - Ta (DM114)



As the power dissipation of a semiconductor chip is limited its package and ambient temperature, this device requires a maximum output current be calculated for a given operating condition. The maximum allowable power consumption (Pd (max)) of this device is calculated as follows:

$$Pd(\max)(Watt) = \frac{(\text{Tj (junction temperature) (max)} - \text{Ta (ambient temperature))(}^{\circ}C)}{\text{Rth (}^{\circ}C/Watt)}$$

Based on the Pd (max), the maximum allowable current can be calculated as follows:

Iout =
$$(Pd - V_{DD} \cdot I_{DD}) / (\# outputs \cdot Vo \cdot Duty)$$

System Configuration Example

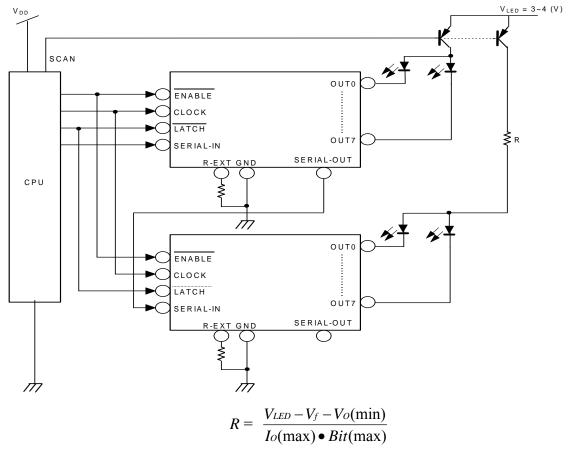
[1] Output current (I_{OUT})

Sink current is set by the external resistor as shown in figure (Iout vs. Rext).

[2] LED supply voltage (V_{LED}) setup

$$V_{LED} = V_{CE} (T_r V_{sat}) + V_f (LED \text{ forward voltage}) + V_O (IC \text{ supply voltage})$$

To prevent too much power dissipated by the device due to higher V_{LED} , an additional R can be used to reduce the Vout when the outputs consume current:

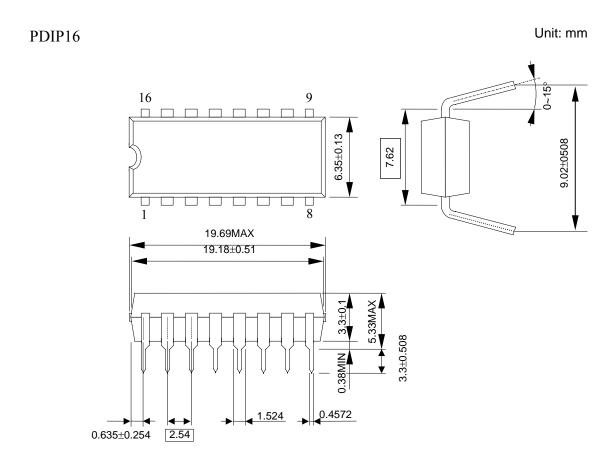


Note

This device has only one ground pin shared by signal, output sink current, and power ground. It is advisable to pattern the ground layout with minimized inductance such that the switching noise induced by the input signals and the output sink current would not cause chip malfunction. To prevent the drivers' outputs from damage by overshoot stress, it is also advisable not to turn off the drivers and scan transistors simultaneously.



Package Outline

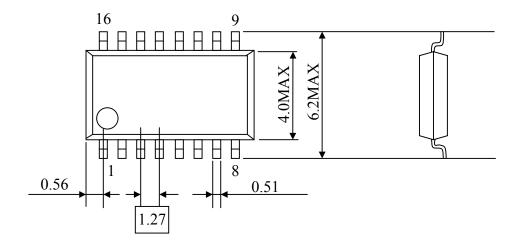


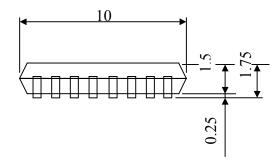
Weight: 1.11g(Typ.)

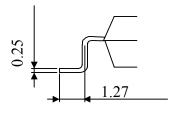


Package Outline

SOP16 Unit: mm

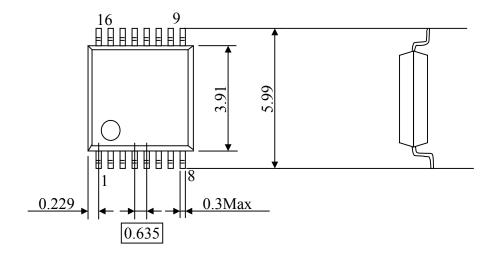


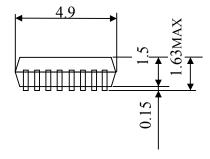


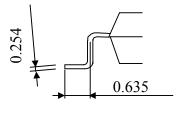


Package Outline

SSOP16 Unit: mm









The products listed herein are designed for ordinary electronic applications, such as electrical appliances, audio-visual equipment, communications devices and so on. Hence, it is advisable that the devices should not be used in medical instruments, surgical implants, aerospace machinery, nuclear power control systems, disaster/crime-prevention equipment and the like. Misusing those products may directly or indirectly endanger human life, or cause injury and property loss.

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